Abstract:

The aim of this assignment is to simulate a chopper circuit supplying a highly inductive and a purely resistive load with an IGBT as a switch. Using PSpice to show the turn-on and turn-off transitions for the voltage, current and power loss in the IGBT. And by calculations the conduction and the switching power losses will be obtained.

Theory:

A chopper is basically a dc to dc converter whose main function/usage is to create adjustable dc voltage from fixed dc voltage sources through the use of semiconductors. In other words, a chopper is a high speed switch which connects and disconnects the load from source at a high rate to get variable or chopped voltage at the output.

The Insulated Gate Bipolar Transistor (IGBT), is a power semiconductor device basically used as a switch, IGBT combines between a Bipolar Junction Transistor (BJT), and a Field Effect Transistor (MOSFET), and it has a simple gate-drive characteristics as MOSFETs with a high-current and low-saturation-voltage capability as BJT. To sum up, an IGBT combines an isolated-gate FET for the control input and a bipolar power transistor as a switch in a single device.

-The average switching power loss in the switch with highly inductive load is: Ps=0.5*fs*Vd*Io*(tc(on) + tc(off))

-Total average switching power loss with resistive load is: Ps=1/6 *fs*Vd*Io*(tc(on) + tc(off))

-The average power loss dissipation during conduction is: Pon= Von*Io*ton*fs

<u>Calculations and Simulations:</u>

First part (Highly Inductive Load):

A chopper circuit supplying a highly inductive load and having an **IGBT** as a switch, has the following parameters: $I_0=25A$, $V_d=400V$, $f_s=15kHz$, $L_s=700nH$ and $t_{on}=30us$. Assume linear voltage and current falls and rises during switching:

I. Calculate The conduction and the switching power losses if $t_{c(on)} = 400$ ns, $t_{c(off)} = 600$ ns, assuming that $V_{on} = 2.5$ V using the appropriate derived formulas.

 $P_{switching} = (\frac{1}{2})*f_{s}*V_{d}*I_{o}*(t_{c,on} + t_{c,off})$ = ($\frac{1}{2}$)*(15k)*(400)*(25)*(1000n) = 75 Watt Pon,conduction = f_{s}*V_{on}*I_{o}*t_{on} = (15k)*(2.5)*(25)*(30*10⁻⁶) = 28.125 Watt

III. The total average power losses in the IGBT: $P_{Total} = P_{switching} + P_{on,conduction} = 103.125$ Watt

II. In ORCAD/PSPICE, simulate a chopper circuit implementing an IGBT (BSM150GB50D) as a switch to supply a highly inductive load which has the following parameters: Io=25A, Vd=400V, fs=15kHz, Ls=700nH and ton=30us. In the results, show the turn-on and turn-off transitions (magnified) for the voltage, current and power losses in the IGBT.





Second Part (Resistive Load):

If the chopper circuit is now supplying a purely resistive load of 15 Ohms (no parallel diode) and implementing the IGBT model. Assume linear voltage and current falls and rises during switching to:

a) Calculate the conduction and the switching power losses if Vd=400V, fs=15kHz, ton=30us, tc(on) =400ns, tc(off)=600ns, Ls=700nH and Von=2.5V using the appropriate derived formulas.

$$\begin{split} P_{switching} &= (\frac{1}{6}) * f_s * V_d * I_o * (t_{c,on} + t_{c,off}) \\ &= (\frac{1}{6}) * (15k) * (400) * (25) * (1000n) \\ &= 25 \text{ Watt} \\ P_{on,conduction} &= f_s * V_{on} * I_o * t_{on} \\ &= (15k) * (2.5) * (25) * (30n) \\ &= 28.125 \text{ Watt} \end{split}$$

c) calculate the average power losses in the IGBT $P_{Total} = P_{switching} + P_{on,conduction} = 53.125$ Watt

b) simulate the circuit in 2) using ORCAD/PSPICE and plot the magnified turn-on and turn off transitions of the voltage, current and power loss in the IGBT.





• <u>Conclusion:</u>

The results obtained from the simulations and calculations show that the power loss in case of a purely resistive load is less than the power loss in case of an inductive load.

By the end of this assignment, a full understanding of chopper circuits was achieved.